

100V PNP MEDIUM POWER LOW SATURATION TRANSISTOR IN SOT223

Features

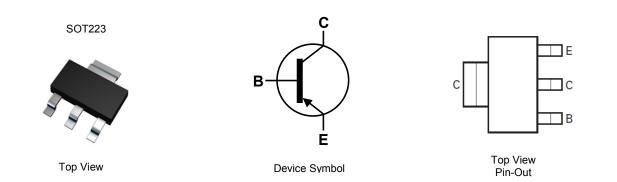
- BV_{CEO} > -100V
- I_C = -5A High Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- Low Saturation Voltage V_{CE(SAT)} < -90mV @ -1A
- $R_{SAT} = 60m\Omega$ for a Low Equivalent On-Resistance
- h_{FE} Specified Up to -10A for a High Gain Hold-Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

Application

- Motor Driving
- Line Switching
- High Side Switches
- Subscriber Line Interface Cards (SLIC)



Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP2013GTA	AEC-Q101	ZXTP2013	7	12	1,000

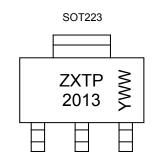
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



ZXTP2013 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 1= 2021) WW or \overline{WW} = Week Code (01~53)



Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-140	V
Collector-Emitter Voltage	V _{CEO}	-100	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	lc	-5	A
Peak Pulse Current	I _{CM}	-10	A

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) Linear Derating Factor	PD	3.0 24	W mW/°C
Power Dissipation (Note 6) Linear Derating Factor	P _D	1.6 12.8	W mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	42	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	78	°C/W
Thermal Resistance Junction to Lead (Note 7)	R _{0JL}	10.48	°C/W
Thermal Resistance Junction to Case (Note 8)	R _{ejc}	13.8	°C/W
Operating and Storage Temperature Range	T _J ,T _{STG}	-55 to +150	°C

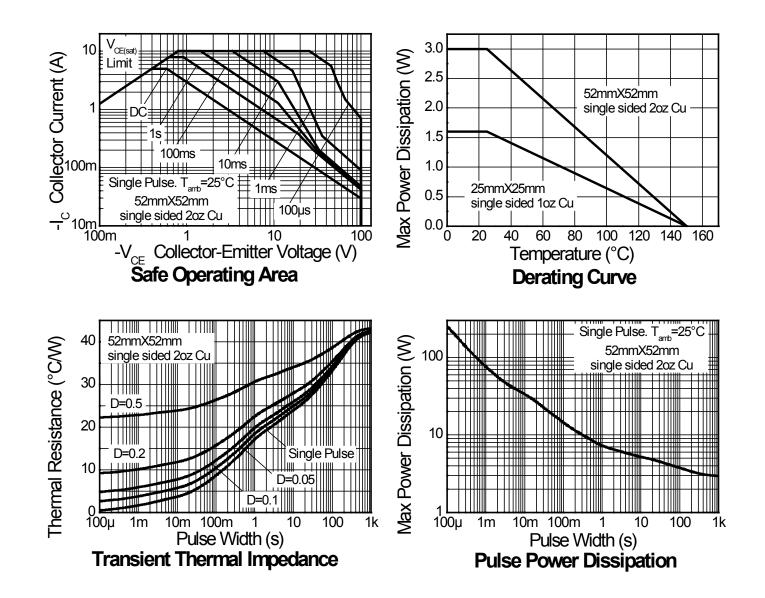
ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
7. Thermal resistance from junction to solder-point (at the end of the collector lead).
8. Thermal resistance from junction to top of the case.
9. Refer to JEDEC specification JESD22-A114 and JESD22-A115. Notes:



Thermal Characteristics and Derating Information





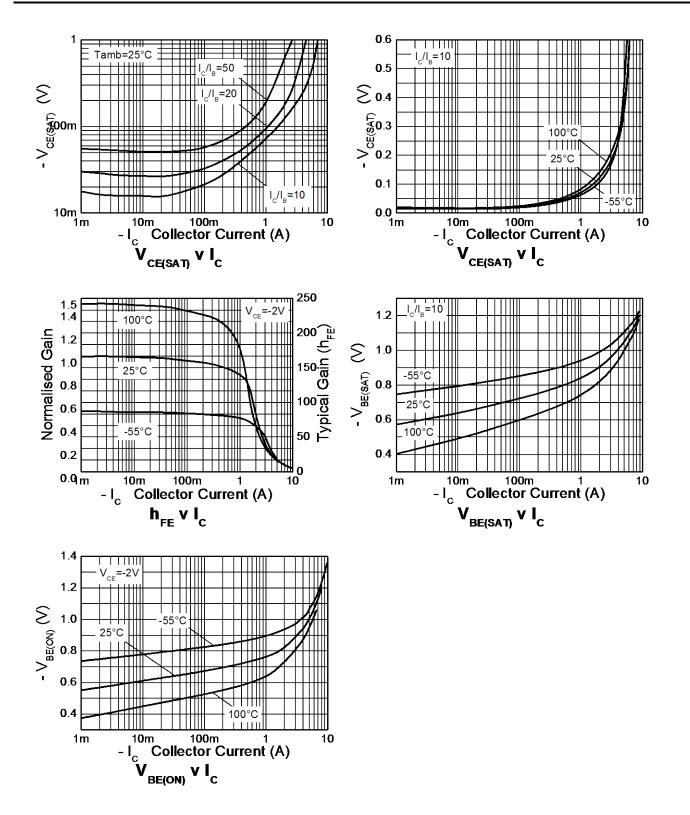
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BV _{CBO}	-140	-160	_	V	I _C = -100μΑ	
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CER}	-140	-160	_	V	I _C = -1μA, R _B ≤ 1kΩ	
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-100	-115	—	V	I _C = -1mA	
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.1	—	V	I _E = -100μA	
Collector Cut-Off Current	I _{CBO}	_	< 1 —	-20 -500	nA nA	V _{CB} = -100V V _{CB} = -100V, T _A = +100°C	
Collector Cut-Off Current	l _{CER} R≤1kΩ		< 1 —	-20 -500	nA nA	V _{CB} = -100V V _{CB} = -100V, T _A = +100°C	
Emitter Cut-Off Current	I _{EBO}	—	< 1	-10	nA	V _{EB} = -6V	
		100	250	_		I _C = -10mA, V _{CE} = -1V	
		100	200	300		I _C = -1A, V _{CE} = -1V	
DC Current Transfer Static Ratio (Note 10)	h _{FE}	25	50	—		I _C = -3A, V _{CE} = -1V	
		15	30	—		I _C = -4A, V _{CE} = -1V	
		-	5	-		I _C = -10A, V _{CE} = -1V	
		—	-20	-30	mV	I _C = -100mA, I _B = -10mA	
Collector-Emitter Saturation Voltage (Note 10)		-	-70	-90		I _C = -1A, I _B = -100mA	
	V _{CE(sat)}	-	-120	-150		I _C = -2A, I _B = -200mA	
		—	-240	-340		I _C = -4A, I _B = -400mA	
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	—	-985	-1100	mV	I _C = -4A, I _B = -400mA	
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	—	-920	-1050	mV	I _C = -4A, V _{CE} = -1V	
Transitional Frequency (Note 10)	f⊤	_	125	—	MHz	$I_{C} = -100 \text{mA}, V_{CE} = -10 \text{V},$ f = 50MHz	
Output Capacitance	C _{obo}	—	42	—	pF	V _{CB} = -10V, f = 1MHz	
Switching Time	t _{on}	—	42	—	ns	V _{CC} = -50V, I _C = -1A,	
	t _{off}	—	540	—	115	I _{B1} = -I _{B2} = -100mA	

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



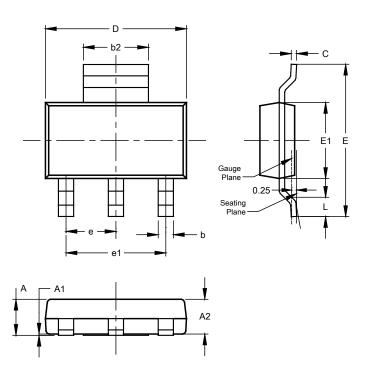
Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

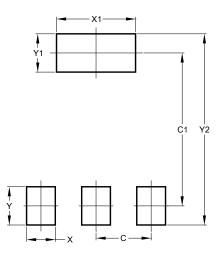


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
с	0.20	0.32			
D	6.30	6.70			
ш	6.70	7.30			
E1	3.30	3.70			
e			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

SOT223 (Type DN)



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